BAT54CW DIODE

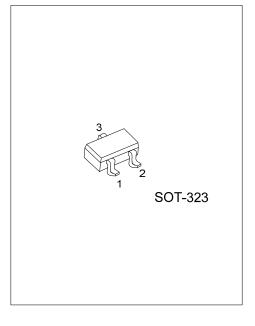
SCHOTTKY BARRIER (DUAL) DIODES

■ DESCRIPTION

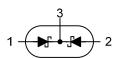
Planar Schottky barrier diodes are encapsulated in the SOT-323 small plastic SMD package. Single diodes and dual diodes with different pin configuration are available.

■ FEATURES

- * Low forward voltage
- * Guard ring protected
- * Small plastic SMD package



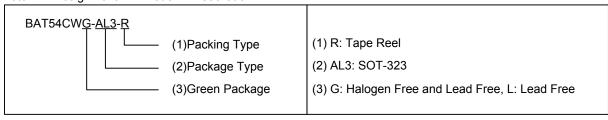
■ SYMBOL



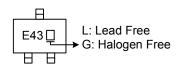
■ ORDERING INFORMATION

Ordering Number		Daalaasa	Pin Assignment			De alsia a	
Lead Free	Halogen Free	Package	1	2	3	Packing	
BAT54CWL-AL3-R	BAT54CWG-AL3-R	SOT-323	A1	A2	K1K2	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode



■ MARKING



www.unisonic.com.tw 1 of 3

BAT54CW DIODE

■ **ABSOLUTE MAXIMUM RATINGS** (T_A = 25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT	
PER DIODE				
Continuous Reverse Voltage	V_R	30	V	
Continuous Forward Current	l _F	200	mA	
Repetitive Peak Forward Current (t _P <1s, δ≤0.5)	I _{FRM}	300	mA	
Non-repetitive Peak Forward Current (t _P <10ms)	I _{FSM}	600	mA	
Junction Temperature	T_J	+125	°C	
Storage Temperature	T _{STG}	-60 ~ +150	°C	
PER DEVICE				
Power Dissipation (T _A ≤25°C)	P_{D}	230	mW	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	625	°C/W

■ **ELECTRICAL CHARACTERISTICS** (T_A = 25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Forward Voltage (See Fig.1)	V _F	$I_F = 0.1 \text{mA}$			240	mV
		I _F = 1mA			320	mV
		I _F = 10mA			400	mV
		I _F = 30mA			500	mV
		I _F = 100mA			800	mV
Reverse Current (See Fig.2)	I_{R}	V _R = 25V			2	μA
Reverse Recovery Time (see Fig.4)	t _{rr}	When switched from I _F =10mA				
		to $I_R = 10$ mA, $R_L = 100\Omega$			5	ns
		measured at I _R = 1mA				
Diode Capacitance (see Fig.3)	C_D	$f = 1 MHz, V_R = 1V;$			10	pF

BAT54CW DIODE

■ TYPICAL CHARACTERISTICS

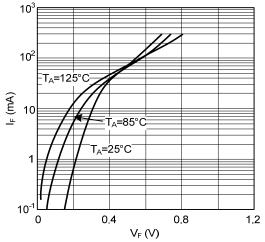


Fig.1 Forward current as a function of forward voltage; typical values.

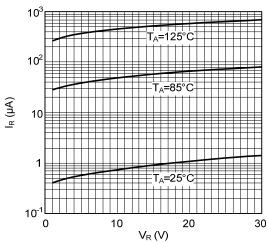


Fig.2 Reverse current as a function of reverse voltage; typical values.

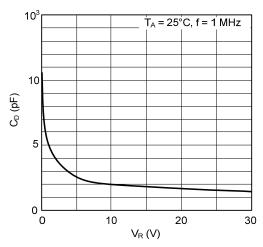


Fig.3 Diode capacitance as a function of reverse voltage; typical values.

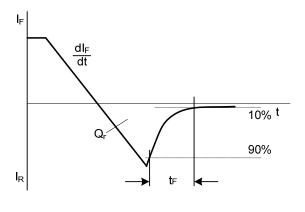


Fig.4 Reverse recovery definitions

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.